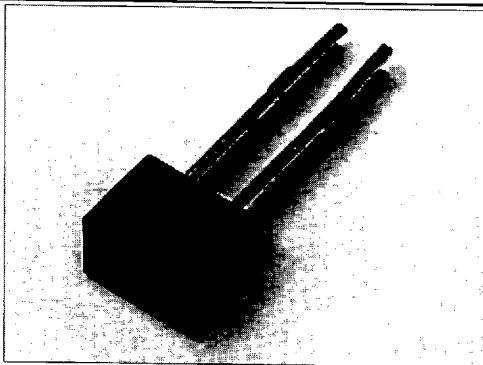


HOA1397

Reflective Sensor

FEATURES

- Choice of phototransistor or photodarlington output
- Low profile for design flexibility
- Unfocused for sensing diffused surfaces



INFRA-10.TIF

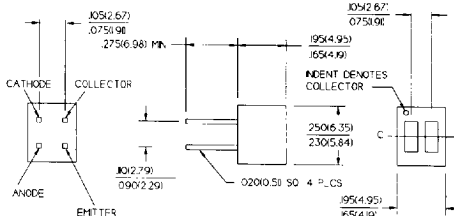
DESCRIPTION

The HOA1397 series consists of an infrared emitting diode and an NPN silicon phototransistor (HOA1397-001, -002) or photodarlington (HOA1397-031, 032) encased side-by-side on parallel axes in a miniature black thermoplastic housing. The detector responds to radiation from the IRED only when a reflective object passes within its field of view. The HOA1397 series employs plastic molded components. For additional component information refer to SEP8507 and SDP8407.

Housing material is polyester. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

OUTLINE DIMENSIONS in inches (mm)

Tolerance 3 plc decimals $\pm 0.010(0.25)$
2 plc decimals $\pm 0.020(0.51)$



DIM_036.cdr

HOA1397

Reflective Sensor

ELECTRICAL CHARACTERISTIC (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	V_F			1.6	V	$I_F=20\text{ mA}$
Reverse Leakage Current	I_R			10	μA	$V_R=3\text{ V}$
DETECTOR						
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	30			V	$I_C=100\text{ }\mu\text{A}$
HOA1397-001, -002		15				
HOA1397-031, -032		5.0				
Emitter-Collector Breakdown Voltage	$V_{(BR)ECO}$				V	$I_E=100\text{ }\mu\text{A}$
Collector Dark Current	I_{CEO}			100	nA	$V_{CE}=10\text{ V}$ $I_F=0$
HOA1397-001, -002				250		
HOA1397-031, -032						
COUPLED CHARACTERISTICS						
On-State Collector Current	$I_{C(ON)}$				mA	$V_{CE}=5\text{ V}$ $I_F=20\text{ mA}$ (1)
HOA1397-001		0.2				
HOA1397-002		0.7				
HOA1397-031		2.0				
HOA1397-032		7.0				
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$			0.4	V	$I_F=20\text{ mA}$ (1) $I_C=30\text{ }\mu\text{A}$ $I_C=90\text{ }\mu\text{A}$ $I_C=250\text{ }\mu\text{A}$ $I_C=880\text{ }\mu\text{A}$
HOA1397-001				0.4		
HOA1397-002				1.1		
HOA1397-031				1.1		
HOA1397-032						
Rise And Fall Time	t_r, t_f				μs	$V_{CC}=5\text{ V}, I_C=1\text{ mA}$ $R_L=1000\text{ }\Omega$ $R_L=100\text{ }\Omega$
HOA1397-001, -002			15			
HOA1397-031, -032			75			

Notes

1. Test surface is a Eastman Kodak Neutral white test card with 90% diffuse reflectance located 0.05 in. (1.27 mm) from the front surface of the device.

ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range -40°C to 85°C

Storage Temperature Range -40°C to 85°C

Soldering Temperature (5 sec) 240°C

IR EMITTER

Power Dissipation 100 mW (1)

Reverse Voltage 3 V

Continuous Forward Current 60 mA

DETECTOR

Collector-Emitter Voltage TRANS. 30 V DARLINGTON 15 V

Emitter-Collector Voltage 5 V 5 V

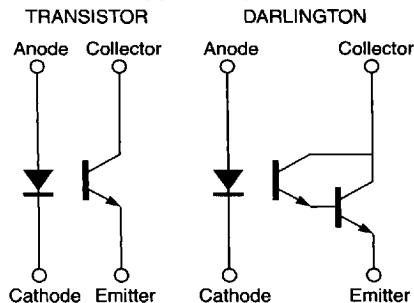
Power Dissipation 100 mW (1) 100 mW (1)

Collector DC Current 30 mA 30 mA

Notes

1. Derate linearly at 0.66 mW/°C above 25°C.

SCHEMATIC



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Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

HOA1397

Reflective Sensor

Fig. 1 IRED Forward Bias Characteristics

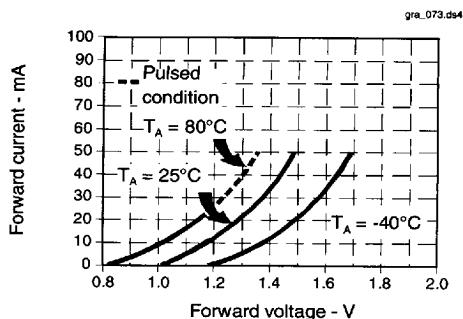


Fig. 2 Non-Saturated Switching Time vs Load Resistance

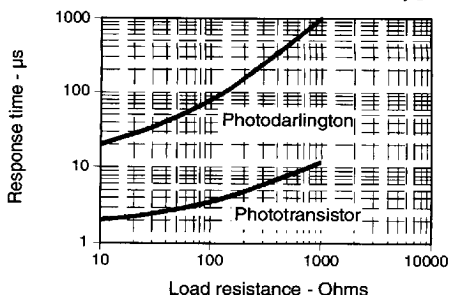


Fig. 3 Dark Current vs Temperature

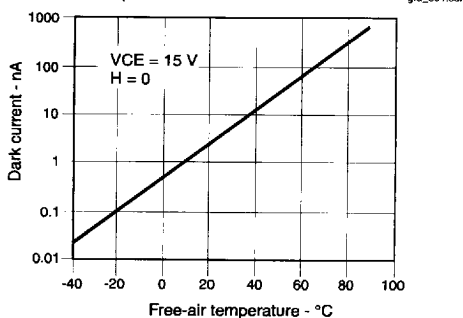


Fig. 4 Collector Current vs Ambient Temperature

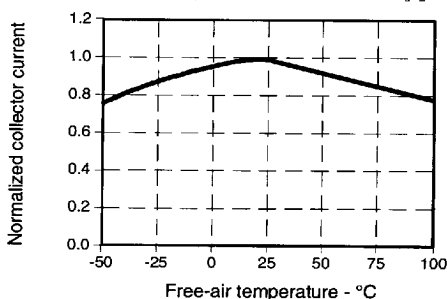


Fig. 5 Collector Current vs Distance to Reflective Surface

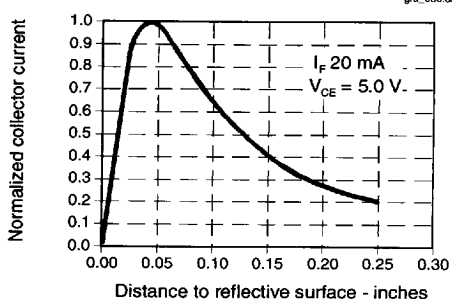
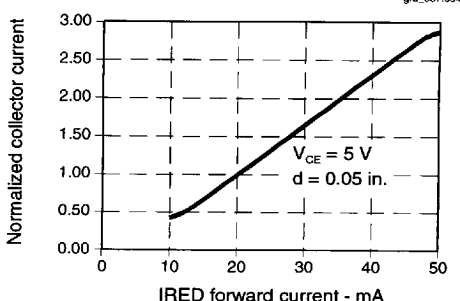


Fig. 6 Collector Current vs IRED Forward Current



All Performance Curves Show Typical Values

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